

100-670520

**U.S. UTILITY Patent Application**

M.14		I.P.E.	PATENT DATE
SCANNED	PD	Q.A.	AA

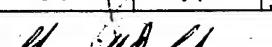
APPLICATION NO. 09/670520	CONT/PRIOR F	CLASS 438	SUBCLASS 517	ART UNIT 2812 28-5	EXAMINER G Lee MSA
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A  
Method for manufacturing semiconductor devices using thermal nitride films as gate insulating films

PTO-2040  
12/89

## ISSUING CLASSIFICATION

<b>TERMINAL DISCLAIMER</b>		<b>DRAWINGS</b>			<b>CLAIMS ALLOWED</b>	
		Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims:	Print.Claim for O.G.
		21	44	5F 6/	15	1
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.		 (Assistant Examiner) 8/24/03 (Date)			<b>NOTICE OF ALLOWANCE MAILED</b>	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____					<b>ISSUE FEE</b>	
					Amount Due	Date Paid
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.		(Primary Examiner) _____ (Date)  (Legal Instruments Examiner) _____ (Date)			<b>ISSUE BATCH NUMBER</b>	
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